

isc Silicon PNP Power Transistors

DESCRIPTION

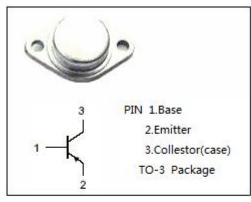
- · Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= -120V(Min)
- · High Power Dissipation-
 - : P_C= 100W(Max)@T_C=25℃
- · Complement to Type 2SD426
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

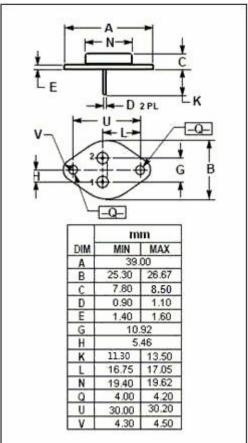
APPLICATIONS

- Designed for power amplifier applications.
- Recommended for 80W high-fidelity audio frequency amplifier output stage.



SYMBOL	PARAMETER VA		UNIT
Vсво	Collector-Base Voltage	-120	V
V _{CEO}	Collector-Emitter Voltage	-120	V
V _{EBO}	Emitter-Base Voltage	-5	V
Ic	Collector Current-Continuous	-12	А
Pc	Collector Power Dissipation @Tc=25°C	100	W
TJ	Junction Temperature		$^{\circ}$ C
T _{stg}	Storage Temperature -65~		$^{\circ}$







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2SB556

ELECTRICAL CHARACTERISTICS

Tj=25℃ unless otherwise specified

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SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = -30mA; I _B = 0	-120			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = -1mA; I _C = 0	-5			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -6A; I _B = -0.6A			-3.0	V
V _{BE(on)}	Base-Emitter On Voltage	Ic= -7A; VcE= -5V			-2.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = -60V; I _E = 0			-0.1	mA
I _{EBO}	Emitter Cutoff Current	V _{EB} = -5V; I _C = 0			-0.1	mA
h _{FE}	DC Current Gain	I _C = -2A; V _{CE} = -5V	40		140	
Сов	Output Capacitance	I _E = 0; V _{CB} = -10V; f= 1MHz		330		pF
f⊤	Current-Gain—Bandwidth Product	I _C = -2A; V _{CE} = -5V		6		MHz

♦ h_{FE} Classifications

R	0
40-80	70-140

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